

BD234  
BD236  
BD238

SILICON  
PNP POWER TRANSISTORS



TO-126 CASE



www.centrasemi.com

**DESCRIPTION:**

The CENTRAL SEMICONDUCTOR BD234, BD236, and BD238 are silicon PNP power transistors designed for medium power amplifier and switching applications.

**MARKING: FULL PART NUMBER**

**MAXIMUM RATINGS:** ( $T_A=25^\circ\text{C}$  unless otherwise noted)

	SYMBOL	BD234	BD236	BD238	UNITS
Collector-Base Voltage	$V_{CB0}$	45	60	100	V
Collector-Emitter Voltage	$V_{CER}$	45	60	100	V
Collector-Emitter Voltage	$V_{CEO}$	45	60	80	V
Emitter-Base Voltage	$V_{EBO}$		5.0		V
Continuous Collector Current	$I_C$		2.0		A
Peak Collector Current	$I_{CM}$		6.0		A
Power Dissipation ( $T_C=25^\circ\text{C}$ )	$P_D$		25		W
Operating and Storage Junction Temperature	$T_J, T_{stg}$		-65 to +150		$^\circ\text{C}$

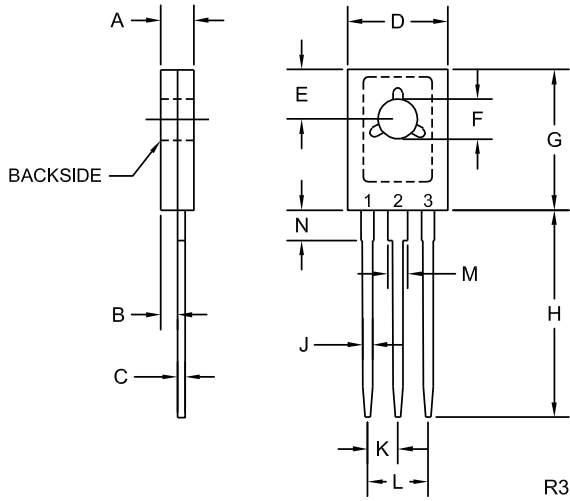
**ELECTRICAL CHARACTERISTICS:** ( $T_C=25^\circ\text{C}$ )

SYMBOL	TEST CONDITIONS	BD234		BD236		BD238		UNITS
		MIN	MAX	MIN	MAX	MIN	MAX	
$I_{CB0}$	$V_{CB}=\text{Rated } V_{CB0}$	-	100	-	100	-	100	$\mu\text{A}$
$I_{EBO}$	$V_{EB}=5.0\text{V}$	-	1.0	-	1.0	-	1.0	mA
$BV_{CEO}$	$I_C=100\text{mA}$	45	-	60	-	80	-	V
$V_{CE(\text{SAT})}$	$I_C=1.0\text{A}, I_B=100\text{mA}$	-	0.6	-	0.6	-	0.6	V
$V_{BE(\text{ON})}$	$V_{CE}=2.0\text{V}, I_C=1.0\text{A}$	-	1.3	-	1.3	-	1.3	V
$h_{FE}$	$V_{CE}=2.0\text{V}, I_C=150\text{mA}$	40	-	40	-	40	-	
$h_{FE}$	$V_{CE}=2.0\text{V}, I_C=1.0\text{A}$	25	-	25	-	25	-	
$f_T$	$V_{CE}=10\text{V}, I_C=250\text{mA}$	3.0	-	3.0	-	3.0	-	MHz

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**TO-126 CASE - MECHANICAL OUTLINE**



SYMBOL	DIMENSIONS			
	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.094	0.110	2.40	2.80
B	0.050		1.27	
C	0.015	0.030	0.38	0.75
D	0.291	0.335	7.40	8.50
E	0.148		3.75	
F	0.118	0.134	3.00	3.40
G	0.413	0.472	10.50	12.00
H	0.618		15.70	
J	0.024	0.035	0.62	0.90
K	0.089		2.25	
L	0.177		4.50	
M	0.045	0.055	1.14	1.40
N	0.083		2.10	

TO-126 (REV:R3)

**LEAD CODE:**

- 1) Emitter
- 2) Collector
- 3) Base

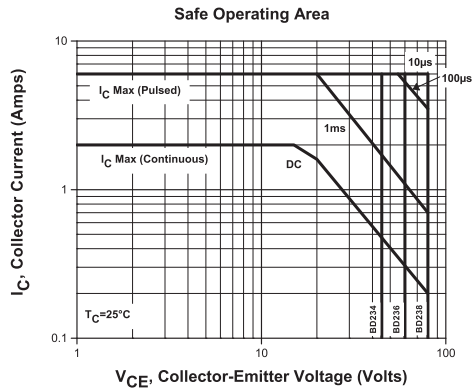
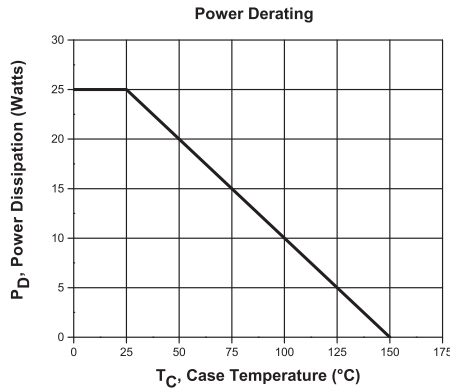
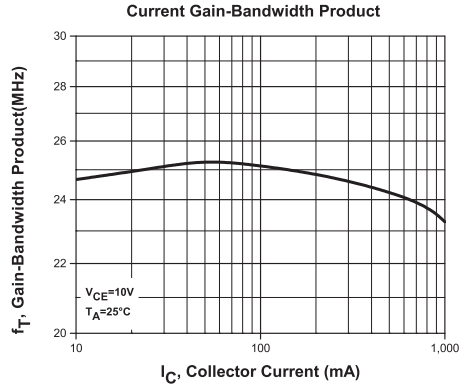
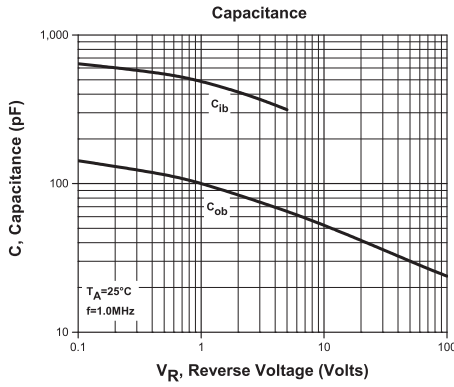
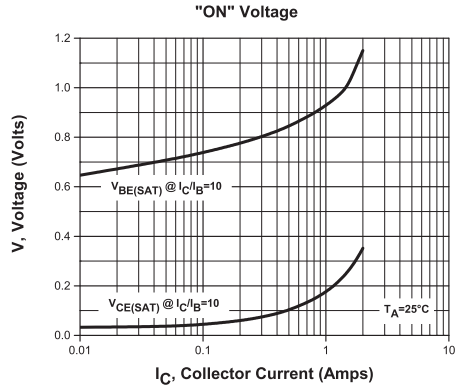
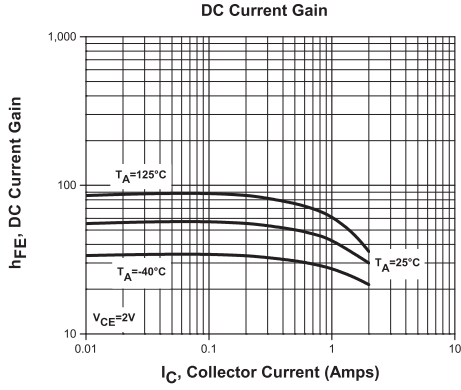
**MARKING: FULL PART NUMBER**

R0 (12-August 2013)

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**TYPICAL ELECTRICAL CHARACTERISTICS**



R0 (12-August 2013)

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- Custom product packing

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- PbSn plating options
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- Application notes
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- Custom product and package development

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